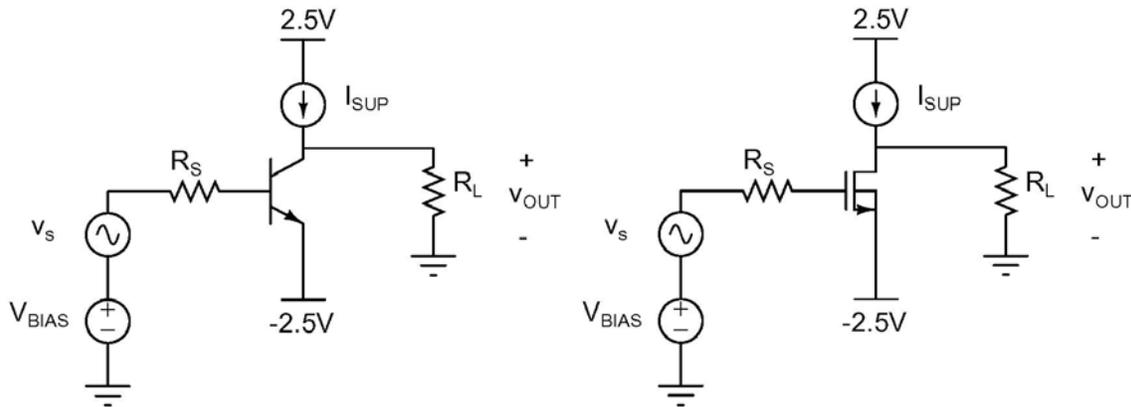


Massachusetts Institute of Technology
Department of Electrical Engineering and Computer Science

6.012 Microelectronic Devices and Circuits
Spring 2007

Homework #7 – Due May 4, 2007

Problem 1:



Common-Emitter	Common-Source
$I_{SUP}=100\mu A$	$I_{SUP}=100\mu A$
$R_S=1k\Omega$	$R_S=1k\Omega$
$R_L=10k\Omega$	$R_L=10k\Omega$
$I_S=10^{-15} A$	$V_{Tn}=1V$
$\beta_F=\beta_o=100$	$\mu_n C_{ox}=50\mu A/V^2$
$V_A=25V$	$\lambda_n=0.1V^{-1}@L=1.5\mu m$
$r_{oc}=\infty$	$r_{oc}=\infty$

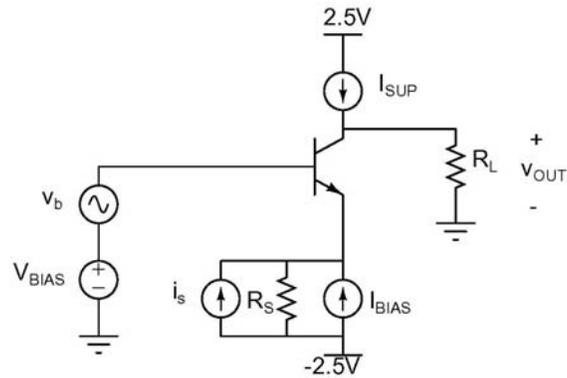
For the Common-Emitter Amplifier:

- a.) Find V_{BIAS} such that $V_{OUT}=0V$
- b.) Find the input resistance R_{in} .
- c.) Find the unloaded voltage gain A_v .
- d.) Find the output resistance R_{out} .
- e.) Draw the two-port model and find the loaded voltage gain v_{out}/v_s .

For the Common-Source Amplifier:

- f.) Choose the length L for the NMOS such that the Common-Source Amplifier has the same output resistance as the Common-Emitter Amplifier.
- g.) Choose the width W for the NMOS such that the Common-Source Amplifier has the same loaded voltage gain as the Common-Emitter Amplifier.
- h.) Find V_{BIAS} such that $V_{OUT}=0V$ for the Common-Source Amplifier designed in parts f and g.

Problem 2:

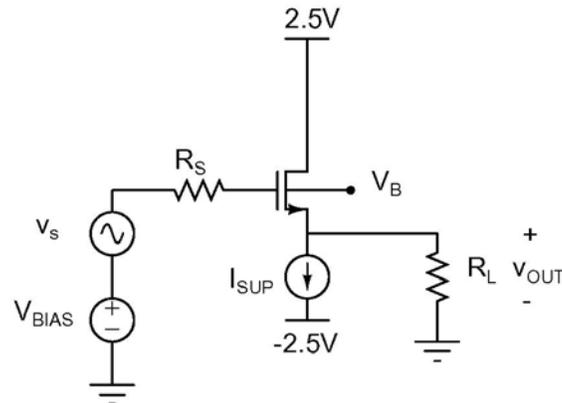


Device Parameters	$I_S=10^{-15}\text{A}$
$I_{SUP}=200\mu\text{A}$	$\beta_F=\beta_o=100$
$R_S=5\text{k}\Omega$	$V_A=25\text{V}$
$R_L=50\text{k}\Omega$	$r_{oc}=\infty$

The DC voltage supply at the base of the npn transistor has a small-signal component added to it which represents feedthrough from other signal lines.

- Find i_{out}/i_s for $v_b=0\text{V}$.
- Find i_{out}/v_b for $i_s=0\text{A}$.
- Let i_{out1} be the portion of i_{out} due to the signal source i_s . Let i_{out2} be the portion of i_{out} due to the signal source v_b . Find the ratio i_{out1}/i_{out2} .
- State whether the value for I_{SUP} , R_S , and R_L should increase, decrease, or stay the same to increase the ratio calculated in part c.

Problem 3:



Device Parameters	
$I_{SUP}=200\mu A$	$W/L=100/2$
$R_S=1k\Omega$	$\mu_n C_{ox}=50\mu A/V^2$
$R_L=100k\Omega$	$\gamma_n=0.5V^{1/2}$
$r_{oc}=\infty$	$V_{T0n}=0.7V$
$2\Phi_p=-0.8V$	$\lambda_n=0.05V^{-1}$

In this problem, we want to compare the small-signal performance and output voltage swing of an NMOS CD amplifier when the backgate terminal is shorted to the source ($V_{BS}=0V$) and when it is tied to the most negative supply ($V_B=-2.5V$).

- Given $I_{SUP}=200\mu A$ and $V_B=-2.5V$, find V_{BIAS} such that $V_{OUT}=0V$.
- What is the maximum and minimum V_{OUT} possible while still keeping the NMOS device in the constant-current region? Assume the current source supply requires at least $0.5V$ across it.
- What is the overall voltage gain, v_{out}/v_s including the effect of R_L ?
- Repeat (a)-(c) for $V_{BS}=0V$.